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PTO/SB/21 (08-00)

09/895,213

Approved for use through 10/31/2002. OMB 0651-0031

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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**Application Number** 

TRANSMITTAL									
FORM (to be used for all correspondence after initial filing)			Filing Date	July 2, 2001					
			First Named Inventor		Shigeo YOSHII et al.				
			Group Art Unit	2826					
			Examiner Name		J.P. MONDT				
Total Number of Pages in This Submission			Attorney Docket Number		740819-592				
		ENCLOSU	RES (check all that apply)						
Fee Transmittal Form Fee Attached			nent Papers Application)		Appeal		Communication to Berferences		
Amendment / Reply		Declaration and Power of Attorney			Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)				
☐ After Final ☐ Affidavits/declaration(s) ☐ Extension of Time Request ☐ Express Abandonment Request ☐ Information Disclosure Statement ☐ Certified Copy of Priority Document(s) ☐ Response to Missing Parts/		Petition Petition Applica Power of Change Termina Request	to Convert to a Provisional		Proprietary Information Status Letter Other Enclosure(s) (please identify below  TECHNOLOGY CENTE  DEC 16 200				DECIA
Incomplete Application								2 7 60 C	790
Response to Missing Parts under 37 CFR 1.52 or 1.53		Remarks  The Commissioner is hereby authorized to charge any additional fees required or credit any overpayments to Deposit Account No. 122380 for the above identified docket number.						fees for the	
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Docket No. 740819-592 IN THE UNITED STATES PATENT AND TRADEMARK OFFICE e Patent Application of Group Art Unit: 2826 Shigeo YOSHII et al. Examiner: J. P. Mondt Serial No. 09/895,213 TECHNOLOGY CENTER 2800 Filed: July 2, 2001 SEMICONDUCTOR LIGHT EMITTING For: DEVICE AND APPARATUS FOR DRIVING THE SAME 09895213 G1/13/2003 JECHILLA 00000004 192380 01 FC:2202 18.00 CH **AMENDMENT** 

Commissioner for Patents Washington, D.C. 20231

Sir:

In response to the Examiner's Office Action mailed September 12, 2002, please consider the following amendments and remarks in connection with the above-identified application.

## IN THE SPECIFICATION:

Please amend the specification as follows:

Page 7

Please replace the second full paragraph with the following:

To attain the foregoing object, a first semiconductor light-emitting device according to the present invention comprises: first and second semiconductor layers each of a first conductivity type; a third semiconductor layer of a second conductivity type provided between the first and second semiconductor layers; an active layer provided between the second and third semiconductor, the active layer emitting light with charge injected therein from the second and third semiconductor layers; and a graded composition layer provided between the active layer and the third semiconductor layer to have a varying composition which is equal to a composition of the active layer at an interface with the active layer and to a composition of the third semiconductor layer at an interface with the third semiconductor layer.

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Please replace the second full paragraph with the following: